| | TRANSMITTAL LETTER (General - Patent Pending) | | Docket No. FIS920000404 (00750452AA) |
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| In Re Application Of: P | | on Sport | Docket No. FIS920000404 (00750452AA) 2 3 2003 Group Art Unit 1765 |
| Serial No. 09/924,318 | Filing Date 08/08/2001 | Examiner B. Tran | Group Art Unit |
| Title: METHOD OF BUILDING A CMOS STRUCTURE ON THIN SOI WITH SOURCE/DRAIN ELECTRODES FORMED BY IN SITU DOPED SELECTIVE AMORPHOUS SILICON | | | |
| TO THE COMMISSIONER FOR PATENTS: | | | |
| Transmitted herewith is: Response to Requirement | nt for Restriction | | |
| as described below ☐ Charge the ☐ Credit any | required. bunt of is attac eby authorized to charge and cre | | 09-0458 |
| Marshall M. Curtis Reg. No. 33,138 Whitham, Curtis & Christo 11491 Sunset Hills Road, Su Reston, VA 20190 (703) 787-9400 | fferson, P.C. nite 340 30743 PATENT TRADEMARK OFFICE | on first class mail u Commissioner fo 22313-1450. | nis document and fee is being deposited with the U.S. Postal Service as nder 37 C.F.R. 1.8 and is addressed to the or Patents, P.O. Box 1450, Alexandria, VA |

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